2SB1050

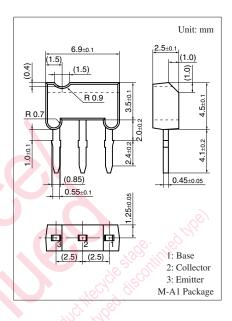
Silicon PNP epitaxial planar type

For low-frequency amplification

Features

- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Large collctor current I_C
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

Absolute Maximum Ratings $T_a = 25^{\circ}C$ Parameter Symbol Rating Unit Collector-base voltage (Emitter open) V_{CBO} -30V V Collector-emitter voltage (Base open) V_{CEO} -20Emitter-base voltage (Collector open) -7 V V_{EBO} Collector current -5 I_C А Peak collector current I_{CP} -8Α Collector power dissipation * P_C 1 W Junction temperature Ti 150 °C Storage temperature -55 to +150 °C T_{stg}



Note) *: Print circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

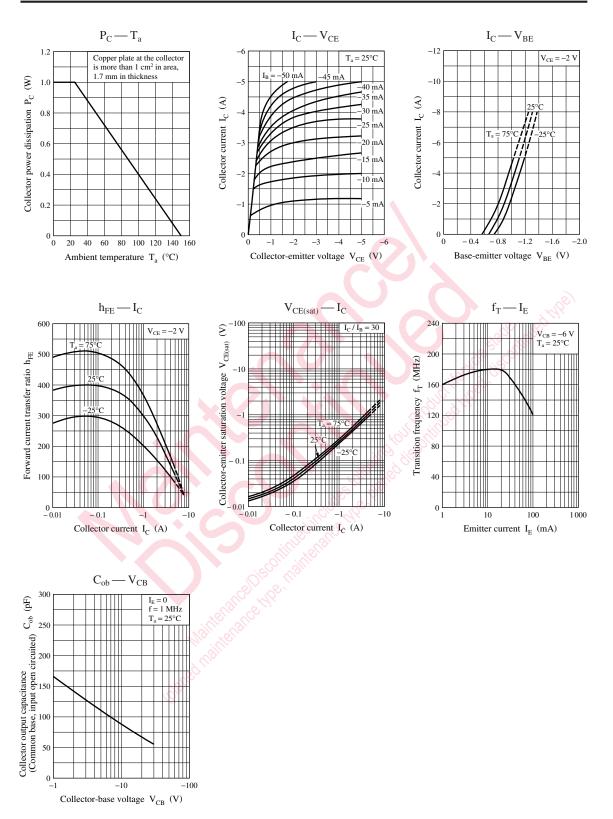
Parameter	Symbol	Conditions		Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -1 \text{ mA}, I_{\rm B} = 0$	-20			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = -10 \ \mu A, \ I_{\rm C} = 0$	-7			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -10 \text{ V}, I_E = 0$			-100	nA
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-100	nA
Forward current transfer ratio *1, 2	h _{FE}	$V_{CE} = -2 V, I_C = -2 A$	90		625	
Collector-emitter saturation voltage *	V _{CE(sat)}	$I_{\rm C} = -3$ A, $I_{\rm B} = -0.1$ A			-1	V
Transition frequency	f _T	$V_{CB} = -6 \text{ V}, I_E = 50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			85	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Rank	Р	Q	R
h _{FE}	90 to135	120 to 205	180 to 625



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